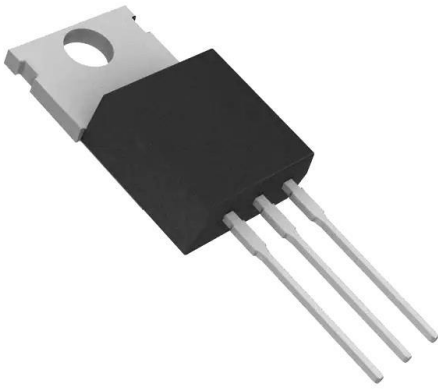


TIP42CTU-T Datasheet

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<https://www.DiGi-Electronics.com>

DiGi Electronics Part Number	TIP42CTU-T-DG
Manufacturer	Fairchild Semiconductor
Manufacturer Product Number	TIP42CTU-T
Description	TRANS BJTS PNP 100V 6A TO220-3 T
Detailed Description	Bipolar (BJT) Transistor PNP 100 V 6 A 3MHz 2 W Th rough Hole TO-220-3



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.

Purchase and inquiry

Manufacturer Product Number:

TIP42CTU-T

Series:

-

Transistor Type:

PNP

Voltage - Collector Emitter Breakdown (Max):

100 V

Current - Collector Cutoff (Max):

700µA

Power - Max:

2 W

Operating Temperature:

150°C (TJ)

Package / Case:

TO-220-3

Manufacturer:

Fairchild Semiconductor

Product Status:

Active

Current - Collector (Ic) (Max):

6 A

Vce Saturation (Max) @ Ib, Ic:

1.5V @ 600mA, 6A

DC Current Gain (hFE) (Min) @ Ic, Vce:

15 @ 3A, 4V

Frequency - Transition:

3MHz

Mounting Type:

Through Hole

Supplier Device Package:

TO-220-3

Environmental & Export classification

RoHS Status:

ROHS3 Compliant

REACH Status:

REACH Affected

Moisture Sensitivity Level (MSL):

Vendor Undefined



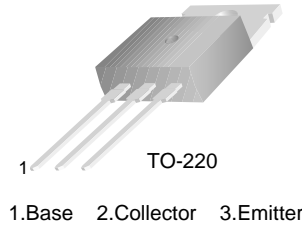
ON Semiconductor®

TIP42 / TIP42C

PNP Epitaxial Silicon Transistor

Features

- Medium Power Linear Switching Applications
- Complement to TIP41 Series



Ordering Information

Part Number	Top Mark	Package	Packing Method
TIP42	TIP42	TO-220 3L (Single Gauge)	Bulk
TIP42C	TIP42C	TO-220 3L (Single Gauge)	Bulk
TIP42CTU	TIP42C	TO-220 3L (Single Gauge)	Rail

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_C = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage	TIP42	-40
		TIP42C	-100
V_{CEO}	Collector-Emitter Voltage	TIP42	-40
		TIP42C	-100
V_{EBO}	Emitter-Base Voltage	-5	V
I_C	Collector Current (DC)	-6	A
I_{CP}	Collector Current (Pulse)	-10	A
I_B	Base Current	-2	A
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{STG}	Storage Temperature Range	-65 to 150	$^\circ\text{C}$

Thermal Characteristics

Values are at $T_C = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Value	Unit
P_C	Collector Dissipation ($T_C = 25^\circ\text{C}$)	65	W
	Collector Dissipation ($T_A = 25^\circ\text{C}$)	2	

Electrical Characteristics

Values are at $T_C = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Max.	Unit
$V_{CEO(sus)}$	Collector-Emitter Sustaining Voltage ⁽¹⁾	TIP42	$I_C = -30\text{ mA}, I_B = 0$	-40	V
		TIP42C		-100	
I_{CEO}	Collector Cut-Off Current	TIP42	$V_{CE} = -30\text{ V}, I_B = 0$	-0.7	mA
		TIP42C	$V_{CE} = -60\text{ V}, I_B = 0$	-0.7	
I_{CES}	Collector Cut-Off Current	TIP42	$V_{CE} = -40\text{ V}, V_{EB} = 0$	-400	μA
		TIP42C	$V_{CE} = -100\text{ V}, V_{EB} = 0$	-400	
I_{EBO}	Emitter Cut-Off Current	$V_{EB} = -5\text{ V}, I_C = 0$		-1	mA
h_{FE}	DC Current Gain ⁽¹⁾		$V_{CE} = -4\text{ V}, I_C = -0.3\text{ A}$	30	
			$V_{CE} = -4\text{ V}, I_C = -3\text{ A}$	15	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage ⁽¹⁾	$I_C = -6\text{ A}, I_B = -600\text{ mA}$		-1.5	V
$V_{BE(on)}$	Base-Emitter On Voltage ⁽¹⁾	$V_{CE} = -4\text{ V}, I_C = -6\text{ A}$		-2.0	V
f_T	Current Gain Bandwidth Product	$V_{CE} = -10\text{ V}, I_C = -500\text{ mA}, f = 1\text{ MHz}$	3.0		MHz

Note:

1. Pulse test: $p_w \leq 300\ \mu\text{s}$, duty cycle $\leq 2\%$.

Typical Performance Characteristics

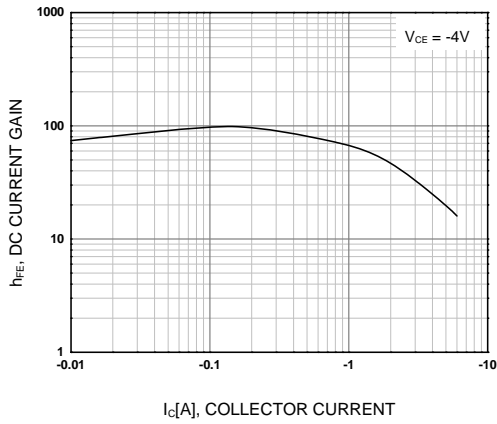


Figure 1. DC Current Gain

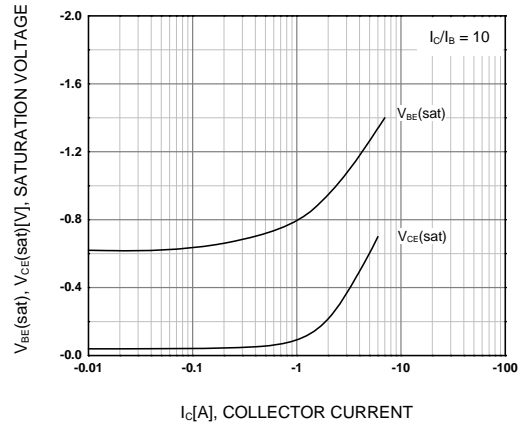


Figure 2. Base-Emitter Saturation Voltage and Collector-Emitter Saturation Voltage

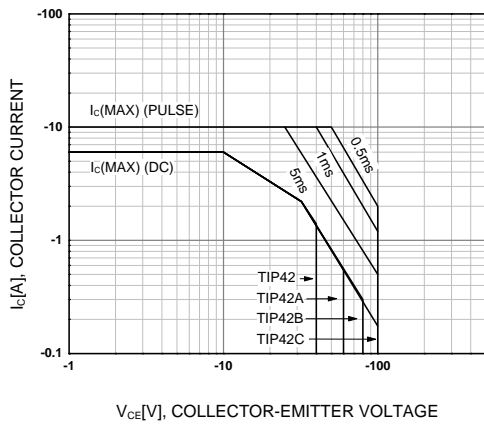


Figure 3. Safe Operating Area

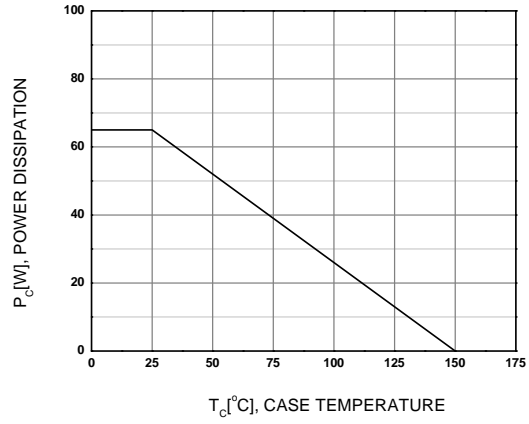


Figure 4. Power Derating

Physical Dimensions

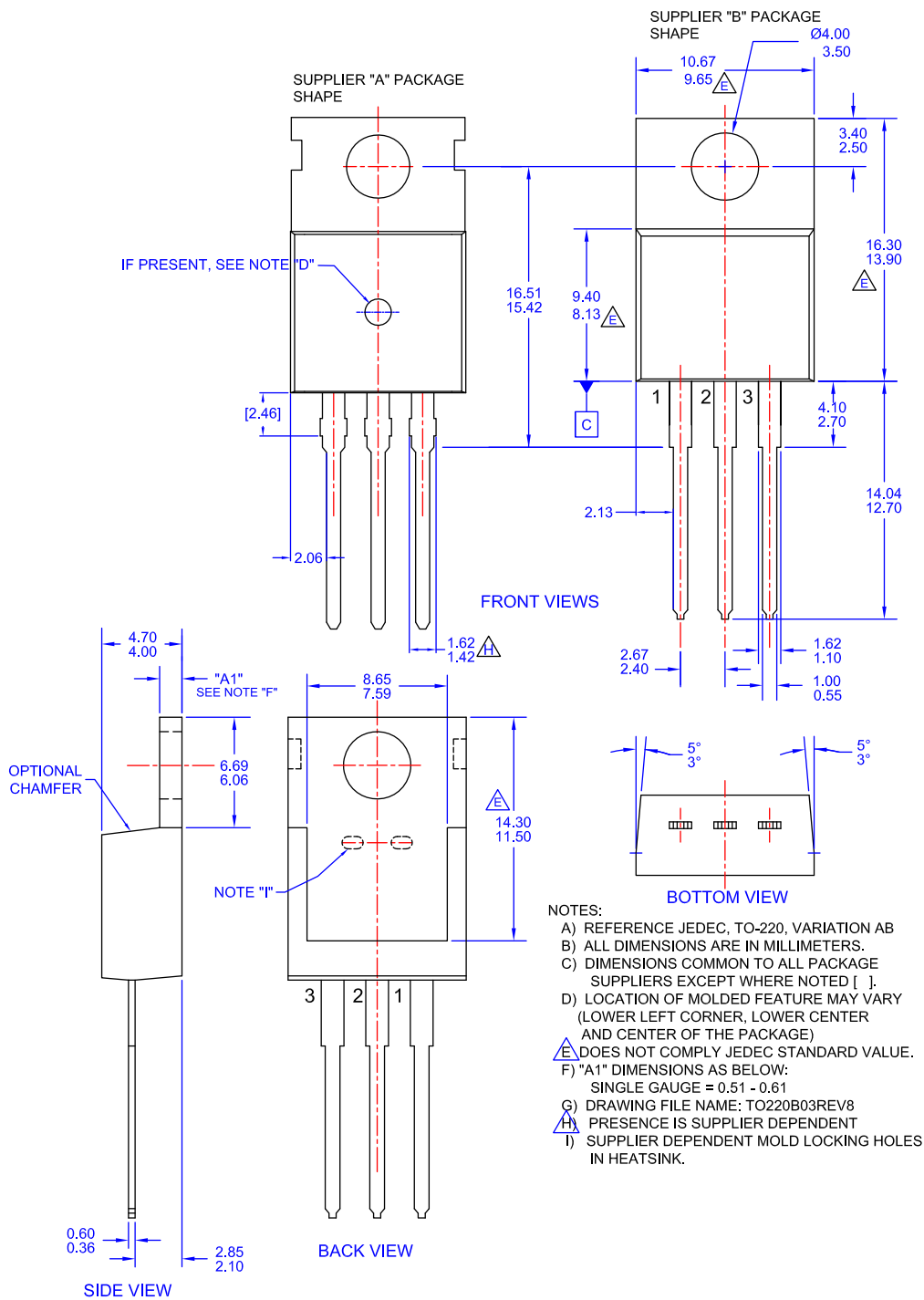



Figure 5. TO-220, MOLDED, 3LEAD, JEDEC VARIATION AB

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